

M 1 0 2 2 L C 1 8 0

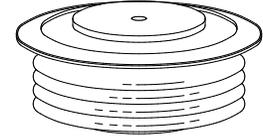
**- Soft Recovery Rectifier
1800 VRRM;**

HIGH POWER FAST RECOVERY RECTIFIER

Features:

- . All Diffused Structure
- . Fast Switching Performance
- . Blocking capability up to 1800 volts
- . Soft Reverse Recovery
- . Rugged Ceramic Hermetic Package
- . Pressure Assembled Device

CASE 3D

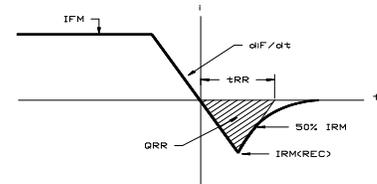


ELECTRICAL CHARACTERISTICS AND RATINGS

Reverse Blocking

Device Type	VRRM (1)	VRSM (1)
M1022LC180	1800	1900

VRRM = Repetitive peak reverse voltage
VRSM = Non repetitive peak reverse voltage (2)



REVERSE RECOVERY CHARACTERISTIC

Notes:

All ratings are specified for Tj=25 °C unless otherwise stated.

(1) All voltage ratings are specified for an applied

50Hz/60zHz sinusoidal waveform over the temperature range -40 to +150 °C.

(2) 10 msec. max. pulse width

(3) Maximum value for Tj = 150 °C.

(4) See parameter definition below :

Repetitive peak reverse leakage	IRRM	100 mA (3)
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Conducting - on state

Parameter	Symbol	Min.	Max.	Typ	Units	Conditions
Average value of on-state current	IF(AV)		460		A	Sinewave, 180° conduction, Tc = 100°C
Average value of on-state current	IF(AV)		1022		A	Sinewave, 180° conduction, Tc = 55°C
RMS value of on-state current	IFRMS		1600		A	Nominal value
Peak one cycle surge (non repetitive) current	IFSM		8500		A	10.0 msec (50Hz), sinusoidal wave-shape, 180° conduction, Tj = 150 °C
I square t	I²t		361000		A²s	8.3 msec and 10.0 msec
Peak on-state voltage	VFM		1.70		V	IFM = 1400 A; Duty cycle ≤0.01%; Tj = 125 °C
Reverse Recovery Current (4)	IRM(REC)		80		A	IFM = 1000 A; dIF/dt = 25 A/μs; Tjmax
Reverse Recovery Charge (4)	Qrr		*	200	μC	IFM = 1000 A; dIF/dt = 25 A/μs; Tjmax
Reverse Recovery Time (4)	tRR		*	3.0	μs	

* For guaranteed maximum values, contact factory

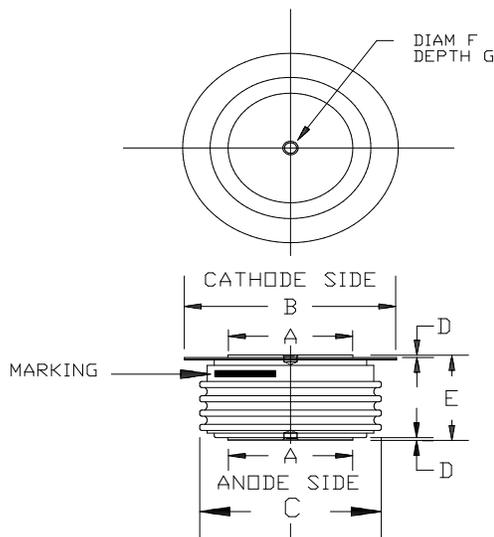
Technical Data :

THERMAL AND MECHANICAL CHARACTERISTICS M1022LC180- Soft Recovery Rectifier

Parameter	Symb ol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	T _j	-40	+150		°C	
Storage temperature	T _{stg}	-40	+150		°C	
Thermal resistance - junction to case	R _{Θ(j-c)}		0.043 0.086		°C/W	Double sided cooled Single sided cooled
Thermal resistance - case to sink	R _{Θ(c-s)}		.015 .030		°C/W	Double sided cooled * Single sided cooled *
Mounting force	P	10.5	19.9		kN	
Weight	W			340	g	

* Mounting surfaces smooth, flat and greased

CASE OUTLINE AND DIMENSIONS



OUTLINE DIMENSIONS - CASE 3D				
DIMENSIONS	Min. mm	Max. mm	Min. In.	Max. In.
DIAM A	33.02	34.29	1.30	1.35
DIAM B	55.88	63.50	2.20	2.50
DIAM C	--	54.61	--	2.15
D	0.76	--	0.03	--
E	25.40	27.18	1.00	1.07
F	3.30	3.81	0.13	0.15
G	1.78	2.03	0.07	0.08

STRIKE DISTANCE = .73 INCH / 18.5 MM MIN.
CREEPAGE DISTANCE = 1.17 INCH / 29.7 MM MIN.